### **OPB916** Series

#### Features:

- Low power consumption
- Data rates to 250 kBaud
- Choice of two logic states and two electrical outputs
- 24" (610 mm) minimum 26 AWG UL listed wires
- Slot width 0.20" (5.08 mm)
- Slot Depth 0.635" (16.13 mm)





#### **Description:**

The **OPB916** series of Photologic® photo integrated circuit switches provide optimum flexibility. Each switch consists of an infrared Light Emitting Diode (LED) and a Photologic® photo integrated circuit, mounted in an opaque housing with clear windows for dust protection. The deep slot allows for a longer reach of the optical path from the 0.650" (16.5 mm) mounting plane. Internal apertures are 0.010" x .060" (.25 mm x 1.52 mm) for the Photologic's "S" side and 0.05" x 0.06" (1.27 mm x 1.52 mm) for the LED "E" side.

Devices in this series exhibit stable performance over supply voltages ranging from 4.5 V to 16.0 V, and may be specified as buffered or inverted with an internal 10 k $\Omega$  pull-up resistor or open collector output. Devices are TTL/LSTTL compatible and can drive up to 10 TTL loads.

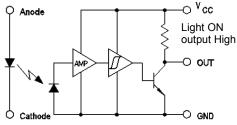
Custom electrical, wire or cabling are available. Contact your local representative or OPTEK for more information.

#### **Applications:**

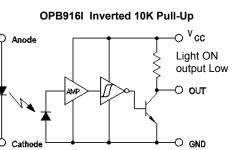
- Mechanical switch replacement
- Speed indication (tachometer)
- Mechanical limit indication
- · Edge sensing

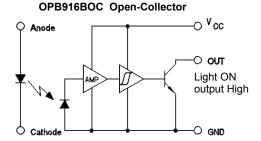
		Ordering Information	n		
Part Number	LED Peak Wavelength	Sensor Photologic®	Slot Width / Depth	Aperture Emitter / Sensor	Lead Length / Wire
OPB916BZ		10K Pull-Up			
OPB916IZ	000	Inv-10K Pull-Up	0.200" / 0.635"	0.05" / 0.01"	24" / 26 AWG Wire
OPB916BOCZ	880 nm	Open-Collector			
OPB916IOCZ		Inv-Open-Collector			

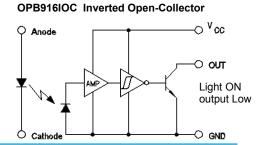
# ColorDescriptionRedAnodeBlackCathodeWhiteVccBlueOutputGreenGround



OPB916B 10K Pull-Up









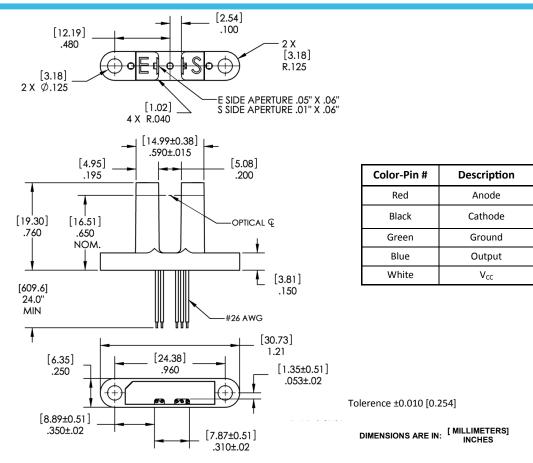
General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

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## **OPB916** Series



<b>Absolute Maximum Ratings</b> (T <sub>A</sub> = 25° C unless otherwise noted)	
Storage & Operating Temperature Range	-40°C to +80°C
Input Infrared LED	
Diode Reverse DC Voltage	2 V
Input Diode Power Dissipation <sup>(2)</sup>	75 mW
Forward DC Current	50 mA
Output Photologic®	
Supply Voltage, V <sub>CC</sub> (not to exceed 3 seconds)	18 V
Voltage at Output Lead (Open Collector Output)	30 V
Output Photologic® Power Dissipation(3)	90 mW

#### Notes:

- (1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.
- (2) Derate linearly 1.67 mW/°C above 25°.
- (3) Derate linearly 2.67 mW/°C above 25°.
- (4) Normal application would be with light source blocked, simulated by  $I_F = 0$  mA.
- (5) All parameters tested using pulse technique.



## **OPB916 Series**

Electrica	l Characteristics (T <sub>A</sub> = 25° C unless other	avice not	tod)			
SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Input Dioc		1		1		1257 5577277575
V <sub>F</sub>	Forward Voltage	-	1.3	1.8	V	I <sub>F</sub> = 20 mA
I <sub>R</sub>	Reverse Current	-	-	100	μΑ	V <sub>R</sub> = 2 V, T <sub>A</sub> = 25° C
Output Pho	otologic® Sensor			I		
V <sub>cc</sub>	Operating DC Supply Voltage	4.5	-	16	V	-
I <sub>CCL</sub>	Low Level Supply Current:  Buffered with 10k pull-up <sup>(1)</sup> Buffered Open-Collector Output <sup>(1)</sup>	-	-	7	mA	$V_{CC} = 16 \text{ V, I}_F = 0 \text{ mA, No Output}$ Load
	Inverted with 10k pull-up: Inverted Open-Collector Output	-	-	7	mA	$V_{CC}$ = 16 V, $I_F$ = 10 mA, No Output Load
І <sub>ссн</sub>	High Level Supply Current: Buffered with 10k pull-up Buffered Open-Collector Output	-	-	6	mA	$V_{CC}$ = 16 V, $I_F$ = 10 mA, No Output Load
	Inverted with 10k pull-up: Inverted Open-Collector Output <sup>(1)</sup>	-	-	6	mA	$V_{CC}$ = 16 V, $I_F$ = 0 mA, No Output Load
V <sub>OL</sub>	Low Level Output Voltage: Buffered with 10k pull-up Buffered Open-Collector Output	-	-	0.4	V	V <sub>CC</sub> = 4.5 V, I <sub>OL</sub> = 16 mA, I <sub>F</sub> = 0 mA
	Inverted with 10k pull-up: Inverted Open-Collector Output	-	-	0.4	V	V <sub>CC</sub> = 4.5 V, I <sub>OL</sub> = 16 mA, I <sub>F</sub> = 10 mA
V <sub>oh</sub>	High Level Output Voltage: Buffered with 10k pull-up	V <sub>cc</sub> -	-	-	V	. $V_{CC} = 4.5 \text{ V to } 16 \text{ V, I}_F = 10 \text{ mA,} \\ I_{OH} = 100  \mu\text{A}$
	Inverted with 10k pull-up:	V <sub>cc</sub> -	-	-	V	$V_{CC} = 4.5 \text{ V to } 16 \text{ V}, I_F = 0 \text{ mA},$
Іон	High Level Output Current:  Buffered with 10k pull-up  Buffered Open-Collector Output	-	1.0	10	μΑ	V <sub>CC</sub> = 4.5 V, I <sub>F</sub> = 10 mA, V <sub>OH</sub> = 30 V
	Inverted with 10k pull-up: Inverted Open-Collector Output <sup>(1)</sup>	-	1.0	10	μΑ	V <sub>CC</sub> = 4.5 V, I <sub>F</sub> = 0 mA, V <sub>OH</sub> = 30 V

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## **OPB916 Series**

Electrical Characteristics (T <sub>A</sub> = 25° C unless otherwise noted)							
SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS	
Output Pho	otologic® Sensor					I	
LED Positive-Going Threshold Current Buffered with 10k pull-up Inverted with 10k pull-up		-	5	10	mA	V <sub>cc</sub> = 5 V, No Output Load	
` ,	Buffered Open-Collector Output Inverted Open-Collector Output <sup>(1)</sup>	-	5	10	mA	V <sub>CC</sub> = 4.5 V, I <sub>OL</sub> = 16 mA	
I <sub>F(+)/</sub> I <sub>F(-)</sub>	Hysteresis	-	1.5	-	-	V <sub>cc</sub> = 5 V	
t <sub>r</sub> t <sub>f</sub>	Rise Time, Fall Time	-	50	-	ns	$V_{CC} = 5 \text{ V}, I_F = 0 \text{ or } 10 \text{ mA},$	
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay	-	3	-	μs	$R_L = 300 \Omega \text{ to 5 V, } C_L = 50 \text{ pF}$	

#### Notes:

Normal application would be with light source blocked, simulated by I<sub>F</sub> = 0 mA.
 All parameters tested using pulse technique.





